

SN54ALS646, SN54ALS648, SN54AS646 SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648 OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

SDAS039F – DECEMBER 1983 – REVISED JANUARY 1995

- Independent Registers for A and B Buses
- Multiplexed Real-Time and Stored Data
- Choice of True or Inverting Data Paths
- Choice of 3-State or Open-Collector Outputs
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (NT) and Ceramic (JT) 300-mil DIPs

DEVICE	OUTPUT	LOGIC
SN54ALS646, SN74ALS646A, 'AS646	3 state	True
SN54ALS648, SN74ALS648A, SN74AS648	3 state	Inverting

description

These devices consist of bus-transceiver circuits with 3-state or open-collector outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate clock (CLKAB or CLKBA) input. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the octal bus transceivers and registers.

Output-enable (\overline{OE}) and direction-control (DIR) inputs control the transceiver functions. In the transceiver mode, data present at the high-impedance port may be stored in either or both registers.

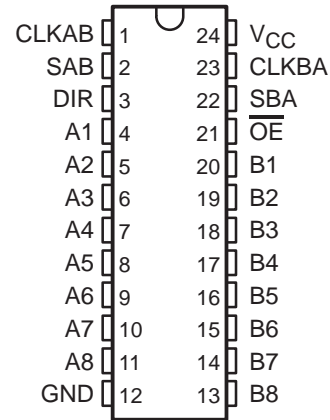
The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode) data. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. DIR determines which bus receives data when \overline{OE} is low. In the isolation mode (\overline{OE} high), A data may be stored in one register and/or B data may be stored in the other register.

When an output function is disabled, the input function is still enabled and can be used to store and transmit data. Only one of the two buses, A or B, may be driven at a time.

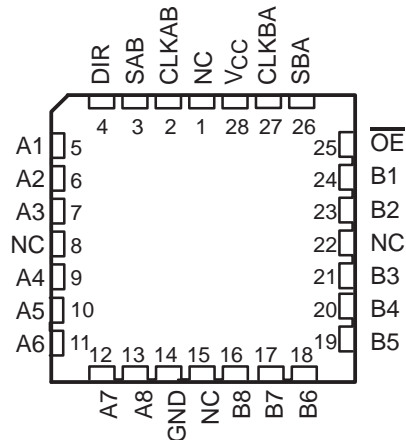
The -1 version of the SN74ALS646A is identical to the standard version, except that the recommended maximum I_{OL} in the -1 version is increased to 48 mA. There are no -1 versions of the SN54ALS646, SN54ALS648, or SN74ALS648A.

The SN54ALS646, SN54ALS648, and SN54AS646 are characterized for operation over the full military temperature range of -55°C to 125°C . The SN74ALS646A, SN74ALS648A, SN74AS646, and SN74AS648 are characterized for operation from 0°C to 70°C .

SN54ALS646, SN54ALS648, SN54AS646 . . . JT PACKAGE
SN74ALS646A, SN74ALS648A, SN74AS646,
SN74AS648 . . . DW OR NT PACKAGE
(TOP VIEW)



SN54ALS646, SN54ALS648, SN54AS646 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

SN54ALS646, SN54ALS648, SN54AS646
 SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
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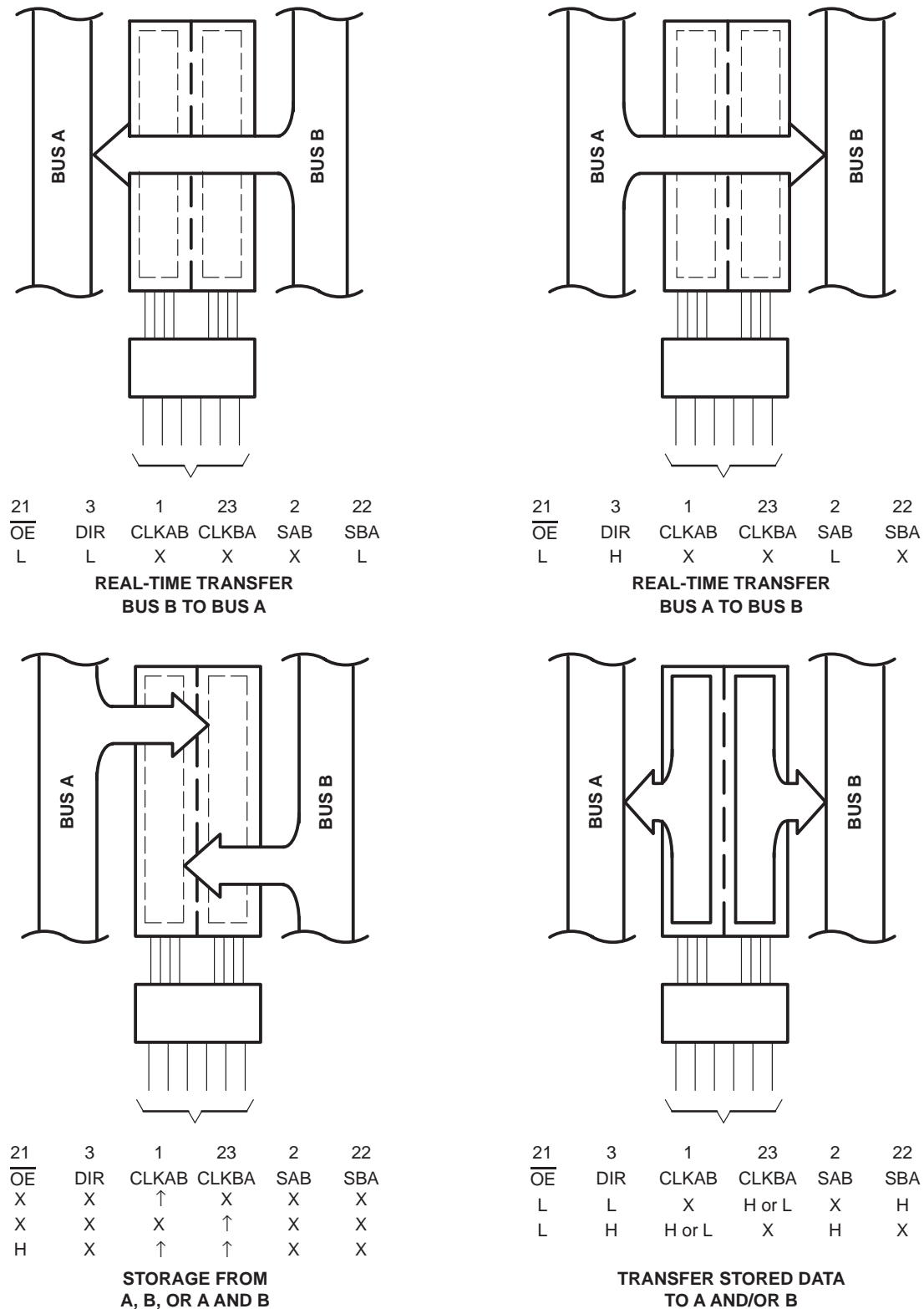


Figure 1. Bus-Management Functions

Pin numbers shown are for the DW, JT, and NT packages.

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SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
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Function Tables

SN54ALS646, SN54AS646, SN74ALS646A, SN74AS646

INPUTS						DATA I/O		OPERATION OR FUNCTION
\overline{OE}	DIR	CLKAB	CLKBA	SAB	SBA	A1–A8	B1–B8	
X	X	↑	X	X	X	Input	Unspecified [†]	Store A, B unspecified [†]
X	X	X	↑	X	X	Unspecified [†]	Input	Store B, A unspecified [†]
H	X	↑	↑	X	X	Input	Input	Store A and B data
H	X	H or L	H or L	X	X	Input disabled	Input disabled	Isolation, hold storage
L	L	X	X	X	L	Output	Input	Real-time B data to A bus
L	L	X	H or L	X	H	Output	Input	Stored B data to A bus
L	H	X	X	L	X	Input	Output	Real-time A data to B bus
L	H	H or L	X	H	X	Input	Output	Stored A data to B bus

[†] The data output functions can be enabled or disabled by various signals at \overline{OE} and DIR. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.

SN54ALS648, SN74ALS648A, SN74AS648

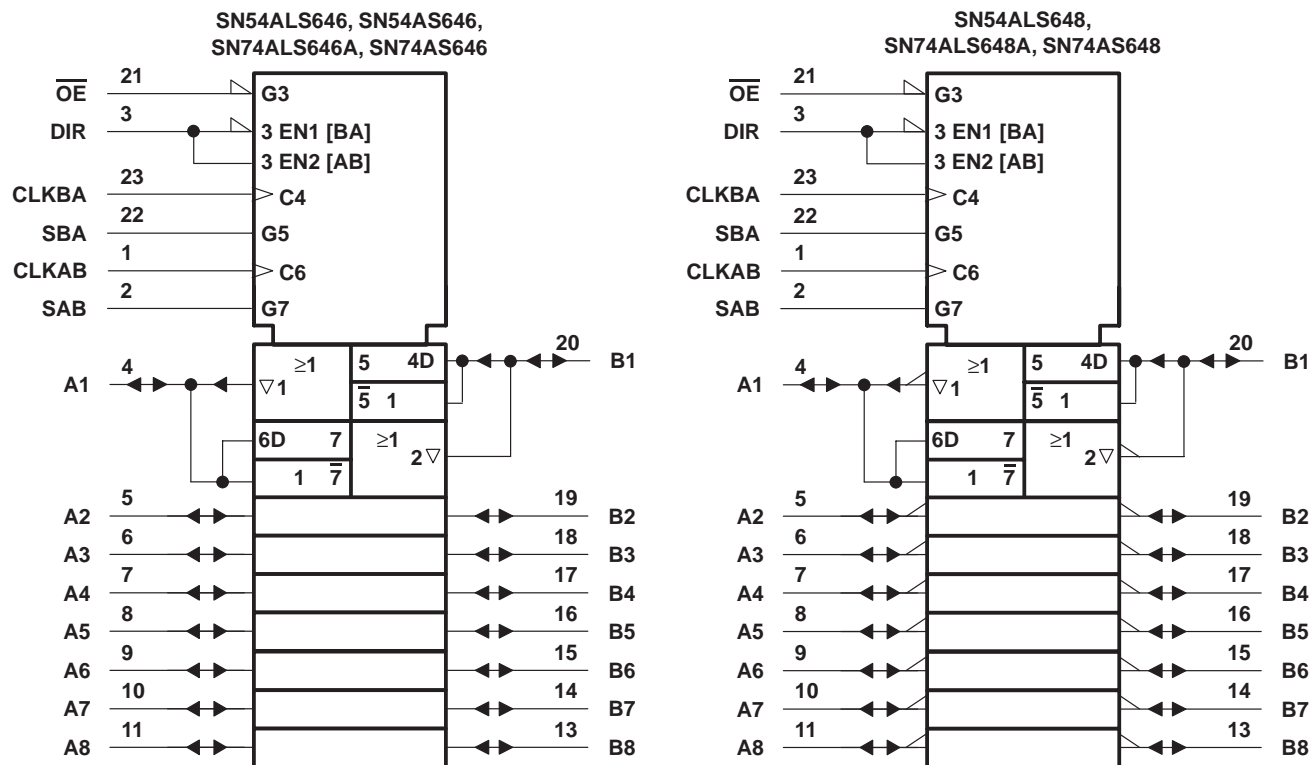
INPUTS						DATA I/O		OPERATION OR FUNCTION
\overline{OE}	DIR	CLKAB	CLKBA	SAB	SBA	A1–A8	B1–B8	
X	X	↑	X	X	X	Input	Unspecified [†]	Store A, B unspecified [†]
X	X	X	↑	X	X	Unspecified [†]	Input	Store B, A unspecified [†]
H	X	↑	↑	X	X	Input	Input	Store A and B data
H	X	H or L	H or L	X	X	Input disabled	Input disabled	Isolation, hold storage
L	L	X	X	X	L	Output	Input	Real-time \overline{B} data to A bus
L	L	X	H or L	X	H	Output	Input	Stored \overline{B} data to A bus
L	H	X	X	L	X	Input	Output	Real-time \overline{A} data to B bus
L	H	H or L	X	H	X	Input	Output	Stored \overline{A} data to B bus

[†] The data output functions can be enabled or disabled by various signals at \overline{OE} and DIR. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.

SN54ALS646, SN54ALS648, SN54AS646 SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648 OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

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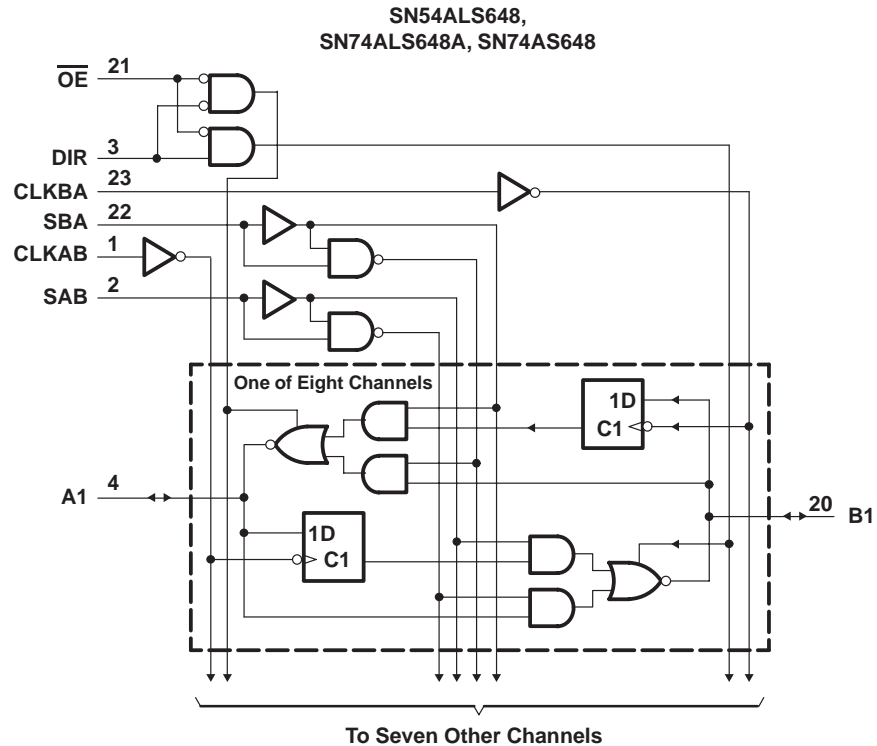
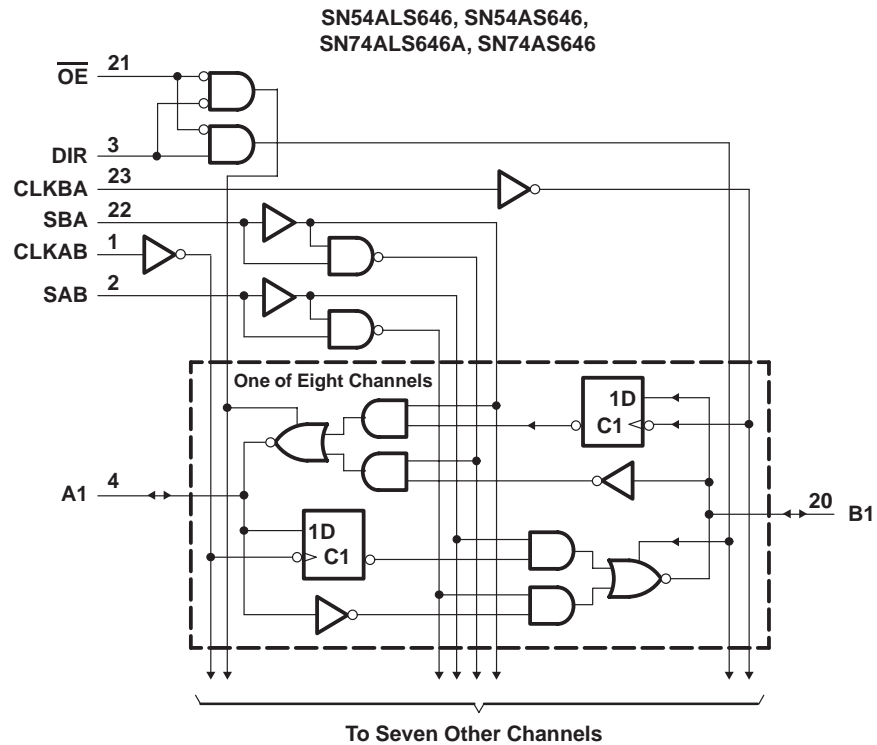
logic symbols†



† These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for the DW, JT, and NT packages.

SN54ALS646, SN54ALS648, SN54AS646
 SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
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logic diagrams (positive logic)



Pin numbers shown are for the DW, JT, and NT packages.

SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC}	7 V
Input voltage, V_I : Control inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, T_A : SN54ALS646	–55°C to 125°C
SN74ALS646A	0°C to 70°C
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN54ALS646			SN74ALS646A			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.7			0.8	V
I_{OH}	High-level output current			–12			–15	mA
I_{OL}	Low-level output current			12			24	mA
							48 [‡]	
f_{clock}	Clock frequency	0		35	0		40	MHz
t_w	Pulse duration, CLKBA or CLKAB high or low	14.5			12.5			ns
t_{su}	Setup time, A before CLKAB \uparrow or B before CLKBA \uparrow	15			10			ns
t_h	Hold time, A after CLKAB \uparrow or B after CLKBA \uparrow	0			0			ns
T_A	Operating free-air temperature	–55		125	0		70	°C

[‡] Applies only to the -1 version and only if V_{CC} is maintained between 4.75 V and 5.25



SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	SN54ALS646			SN74ALS646A			UNIT
			MIN	TYP†	MAX	MIN	TYP†	MAX	
V _{IK}		V _{CC} = 4.5 V, I _I = −18 mA	−1.2			−1.2			V
V _{OH}		V _{CC} = 4.5 V to 5.5 V, I _{OH} = −0.4 mA	V _{CC} − 2			V _{CC} − 2			V
		V _{CC} = 4.5 V	I _{OH} = −3 mA		2.4	3.2	2.4	3.2	
			I _{OH} = −12 mA		2				
			I _{OH} = −15 mA				2		
V _{OL}		V _{CC} = 4.5 V	I _{OL} = 12 mA		0.25	0.4	0.25	0.4	V
			I _{OL} = 24 mA				0.35	0.5	
			I _{OL} = 48 mA‡				0.35	0.5	
I _I	Control inputs	V _{CC} = 5.5 V	V _I = 7 V		0.1		0.1		mA
	A or B ports		V _I = 5.5 V		0.1		0.1		
I _{IH}	Control inputs	V _{CC} = 5.5 V, V _I = 2.7 V	20			20			μA
	A or B ports§		20			20			
I _{IL}	Control inputs	V _{CC} = 5.5 V, V _I = 0.4 V	−0.2			−0.2			mA
	A or B ports§		−0.2			−0.2			
I _O ¶		V _{CC} = 5.5 V, V _O = 2.25 V	−20		−112		−30 −112		mA
I _{CC}		V _{CC} = 5.5 V	Outputs high		47 76		47 76		mA
			Outputs low		55 88		55 88		
			Outputs disabled		55 88		55 88		

† All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ Applies only to the -1 version and only if V_{CC} is maintained between 4.75 V and 5.25

§ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

¶ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS} .

SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
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switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 4.5 V to 5.5 V, C _L = 50 pF, R ₁ = 500 Ω, R ₂ = 500 Ω, T _A = MIN to MAX†				UNIT
			SN54ALS646		SN74ALS646A		
			MIN	MAX	MIN	MAX	
f _{max}			35		40		MHz
t _{PLH}	CLKBA or CLKAB	A or B	10	35	7	30	ns
t _{PHL}			5	20	5	17	
t _{PLH}	A or B	B or A	5	22	3	20	ns
t _{PHL}			3	15	3	12	
t _{PLH}	SBA or SAB‡ (stored data low)	A or B	10	40	7	35	ns
t _{PHL}			5	23	5	20	
t _{PLH}	SBA or SAB‡ (stored data high)	A or B	8	30	6	25	ns
t _{PHL}			5	24	5	20	
t _{PZH}	OE	A or B	3	20	2	17	ns
t _{PZL}			5	22	4	20	
t _{PHZ}	OE	A or B	1	12	1	10	ns
t _{PLZ}			1	20	2	16	
t _{PZH}	DIR	A or B	5	38	3	30	ns
t _{PZL}			5	30	4	25	
t _{PHZ}	DIR	A or B	1	12	1	10	ns
t _{PLZ}			2	21	2	16	

† For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

**SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS**

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC}	7 V
Input voltage, V_I : Control inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, T_A : SN54ALS648	–55°C to 125°C
SN74ALS648A	0°C to 70°C
Storage temperature range	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN54ALS648			SN74ALS648A			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.7			0.8	V
I_{OH}	High-level output current			–12			–15	mA
I_{OL}	Low-level output current			12			24	mA
f_{clock}	Clock frequency	0		35	0		40	MHz
t_w	Pulse duration, CLKBA or CLKAB high or low	14.5			12.5			ns
t_{su}	Setup time, A before CLKAB↑ or B before CLKBA↑	15			10			ns
t_h	Hold time, A after CLKAB↑ or B after CLKBA↑	0			0			ns
T_A	Operating free-air temperature	–55		125	0		70	°C



SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54ALS648		SN74ALS648A		UNIT
				MIN	TYP†	MAX	MIN	
V _{IK}		V _{CC} = 4.5 V, I _I = −18 mA		−1.2		−1.2		V
V _{OH}		V _{CC} = 4.5 V to 5.5 V, I _{OH} = −0.4 mA		V _{CC} − 2		V _{CC} − 2		V
		V _{CC} = 4.5 V	I _{OH} = −3 mA	2.4	3.2	2.4	3.2	
			I _{OH} = −12 mA	2				
			I _{OH} = −15 mA			2		
V _{OL}		V _{CC} = 4.5 V	I _{OL} = 12 mA	0.25	0.4	0.25	0.4	V
			I _{OL} = 24 mA			0.35	0.5	
I _I	Control inputs	V _{CC} = 5.5 V	V _I = 7 V	0.1		0.1		mA
	A or B ports		V _I = 5.5 V	0.1		0.1		
I _{IH}	Control inputs	V _{CC} = 5.5 V, V _I = 2.7 V	20		20		μA	
	A or B ports‡		20		20			
I _{IL}	Control inputs	V _{CC} = 5.5 V, V _I = 0.4 V	−0.2		−0.2		mA	
	A or B ports‡		−0.2		−0.2			
I _O §		V _{CC} = 5.5 V, V _O = 2.25 V	−20	−112	−30	−112	mA	
I _{CC}		V _{CC} = 5.5 V	Outputs high	47	76	47	76	mA
			Outputs low	57	88	57	88	
			Outputs disabled	57	88	57	88	

† All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS} .

SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
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switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 4.5 V to 5.5 V, C _L = 50 pF, R ₁ = 500 Ω, R ₂ = 500 Ω, T _A = MIN to MAX†				UNIT
			SN54ALS648		SN74ALS648A		
			MIN	MAX	MIN	MAX	
f _{max}			35		40		MHz
t _{PLH}	CLKBA or CLKAB	A or B	8	39	7	33	ns
t _{PHL}			5	23	5	20	
t _{PLH}	A or B	B or A	3	20	2	17	ns
t _{PHL}			2	12	2	10	
t _{PLH}	SBA or SAB‡ (stored data low)	A or B	5	44	5	39	ns
t _{PHL}			4	26	4	22	
t _{PLH}	SBA or SAB‡ (stored data high)	A or B	6	30	6	25	ns
t _{PHL}			6	25	6	21	
t _{PZH}	OE	A or B	4	25	2	22	ns
t _{PZL}			4	25	4	22	
t _{PHZ}	OE	A or B	1	12	1	10	ns
t _{PLZ}			2	21	2	15	
t _{PZH}	DIR	A or B	4	35	2	27	ns
t _{PZL}			3	25	3	19	
t _{PHZ}	DIR	A or B	1	17	1	14	ns
t _{PLZ}			2	22	2	15	

† For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC}	7 V
Input voltage, V_I : Control inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, T_A : SN54AS646	–55°C to 125°C
SN74AS646	0°C to 70°C
Storage temperature range	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SN54AS646			SN74AS646			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC}	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V _{IH}	High-level input voltage		2			2			V
V _{IL}	Low-level input voltage		0.8			0.8			V
I _{OH}	High-level output current		−12			−15			mA
I _{OL}	Low-level output current		32			48			mA
f _{clock} *	Clock frequency		0	75		0	90		MHz
t _w *	Pulse duration	CLKBA or CLKAB high	6			5			ns
		CLKBA or CLKAB low	7			6			
t _{su} *	Setup time, A before CLKAB↑ or B before CLKBA↑		7			6			ns
t _h *	Hold time, A after CLKAB↑ or B before CLKBA		0			0			ns
T _A	Operating free-air temperature		−55			125			°C

* On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	SN54AS646			SN74AS646			UNIT
			MIN	TYP†	MAX	MIN	TYP†	MAX	
V _{IK}		V _{CC} = 4.5 V, I _I = −18 mA	−1.2			−1.2			V
V _{OH}		V _{CC} = 4.5 V to 5.5 V, I _{OH} = −2 mA	V _{CC} − 2			V _{CC} − 2			V
		V _{CC} = 4.5 V	I _{OH} = −3 mA		2.4	3.2	2.4	3.2	
			I _{OH} = −12 mA		2				
			I _{OH} = −15 mA				2		
V _{OL}		V _{CC} = 4.5 V	I _{OL} = 32 mA		0.25	0.5			V
			I _{OL} = 48 mA				0.35	0.5	
I _I	Control inputs	V _{CC} = 5.5 V, V _I = 7 V	0.1			0.1			mA
	A or B ports	V _{CC} = 5.5 V, V _I = 5.5 V	0.1			0.1			
I _{IH}	Control inputs	V _{CC} = 5.5 V, V _I = 2.7 V	20			20			μA
	A or B ports‡		70			70			
I _{IL}	Control input	V _{CC} = 5.5 V, V _I = 0.4 V	−0.5			−0.5			mA
	A or B ports‡		−0.75			−0.75			
I _O §		V _{CC} = 5.5 V, V _O = 2.25 V	−30	−112		−30	−112		mA
I _{CC}		V _{CC} = 5.5 V	Outputs high		120	195	120	195	mA
			Outputs low		130	211	130	211	
			Outputs disabled		130	211	130	211	

† All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS} .

SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS
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switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 4.5 V to 5.5 V, C _L = 50 pF, R ₁ = 500 Ω, R ₂ = 500 Ω, T _A = MIN to MAX†				UNIT
			SN54AS646		SN74AS646		
			MIN	MAX	MIN	MAX	
f _{max} *			75		90		MHz
t _{PLH}	CLKBA or CLKAB	A or B	2	9.5	2	8.5	ns
t _{PHL}			2	10	2	9	
t _{PLH}	A or B	B or A	2	11.5	2	9	ns
t _{PHL}			1	8	1	7	
t _{PLH}	SBA or SAB‡	A or B	2	13.5	2	11	ns
t _{PHL}			2	11	2	9	
t _{PZH}	\overline{OE}	A or B	2	11	2	9	ns
t _{PZL}			3	15	3	14	
t _{PHZ}	\overline{OE}	A or B	2	11	2	9	ns
t _{PLZ}			2	11	2	9	
t _{PZH}	DIR	A or B	3	21	3	16	ns
t _{PZL}			3	24	3	18	
t _{PHZ}	DIR	A or B	2	12	2	10	ns
t _{PLZ}			2	12	2	10	

* On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.

† For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

**SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS**

SDAS039F – DECEMBER 1983 – REVISED JANUARY 1995

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC}	7 V
Input voltage, V_I : Control inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, T_A : SN74AS648	0°C to 70°C
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN74AS648			UNIT
		MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	V
V_{IH}	High-level input voltage	2			V
V_{IL}	Low-level input voltage			0.8	V
I_{OH}	High-level output current			–15	mA
I_{OL}	Low-level output current			48	mA
f_{clock}	Clock frequency	0		90	MHz
t_w	Pulse duration	CLKBA or CLKAB high		5	ns
		CLKBA or CLKAB low		6	
t_{su}	Setup time, A before CLKAB \uparrow or B before CLKBA \uparrow	6			ns
t_h	Hold time, A after CLKAB \uparrow or B before CLKBA	0			ns
T_A	Operating free-air temperature	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN74AS648		UNIT
				MIN	TYP [‡]	MAX
V_{IK}		$V_{CC} = 4.5\text{ V}$, $I_I = -18\text{ mA}$				–1.2
V_{OH}		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$, $I_{OH} = -2\text{ mA}$		$V_{CC} - 2$		V
		$V_{CC} = 4.5\text{ V}$, $I_{OH} = -3\text{ mA}$		2.4	3.2	
		$V_{CC} = 4.5\text{ V}$, $I_{OH} = -15\text{ mA}$		2		
V_{OL}		$V_{CC} = 4.5\text{ V}$, $I_{OL} = 48\text{ mA}$		0.35	0.5	V
I_I	Control inputs	$V_{CC} = 5.5\text{ V}$	$V_I = 7\text{ V}$			0.1
	A or B ports		$V_I = 5.5\text{ V}$			0.1
I_{IH}	Control inputs	$V_{CC} = 5.5\text{ V}$, $V_I = 2.7\text{ V}$				20
	A or B ports [§]					70
I_{IL}	Control input	$V_{CC} = 5.5\text{ V}$, $V_I = 0.4\text{ V}$				–0.5
	A or B ports [§]					–0.75
I_{O}^{\parallel}		$V_{CC} = 5.5\text{ V}$, $V_O = 2.25\text{ V}$		–30		–112
I_{CC}		$V_{CC} = 5.5\text{ V}$	Outputs high		110	185
			Outputs low		120	195
			Outputs disabled		120	195

[‡] All typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

[§] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

^{||} The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS} .



SN54ALS646, SN54ALS648, SN54AS646
SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648
OCTAL BUS TRANSCEIVERS AND REGISTERS WITH 3-STATE OUTPUTS
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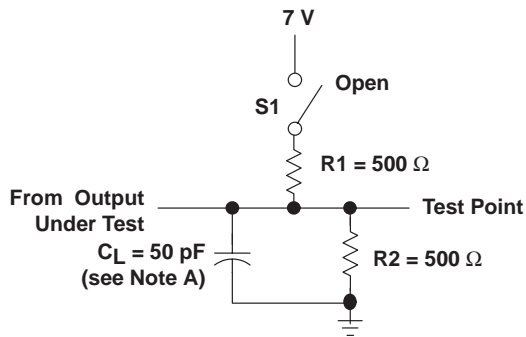
switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 4.5 V to 5.5 V, C _L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T _A = MIN to MAX†		UNIT
			SN74AS648		
			MIN	MAX	
f _{max}			90		MHz
t _{PLH}	CLKBA or CLKAB	A or B	2	8.5	ns
t _{PHL}			2	9	
t _{PLH}	A or B	B or A	2	8	ns
t _{PHL}			1	7	
t _{PLH}	SBA or SAB‡	A or B	2	11	ns
t _{PHL}			2	9	
t _{PZH}	\overline{OE}	A or B	2	9	ns
t _{PZL}			3	15	
t _{PHZ}	\overline{OE}	A or B	2	9	ns
t _{PLZ}			2	9	
t _{PZH}	DIR	A or B	3	16	ns
t _{PZL}			3	18	
t _{PHZ}	DIR	A or B	2	10	ns
t _{PLZ}			2	10	

† For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

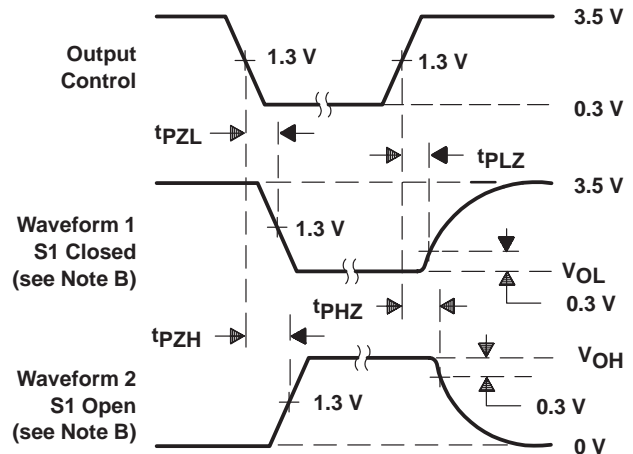
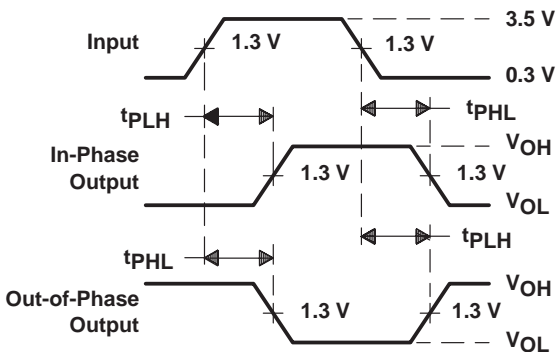
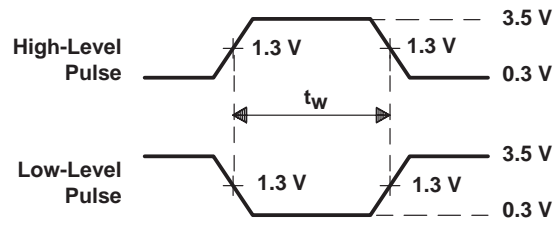
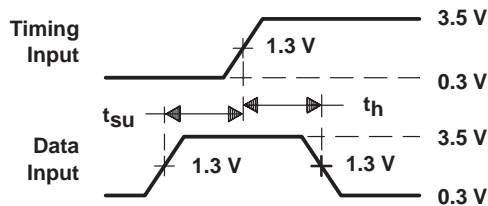
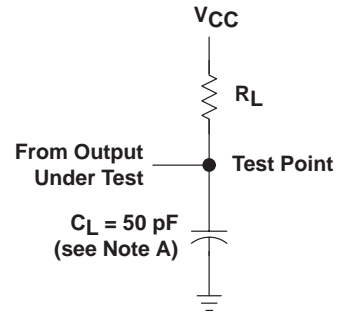
‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

PARAMETER MEASUREMENT INFORMATION



SWITCH POSITION TABLE

TEST	S1
t_{PLH}	Open
t_{PHL}	Open
t_{PZH}	Open
t_{PZL}	Closed
t_{PHZ}	Open
t_{PLZ}	Closed



- NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2 \text{ ns}$, $t_f \leq 2 \text{ ns}$.
D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuits and Voltage Waveforms

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-8759501LA	Active	Production	CDIP (JT) 24	15 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8759501LA SNJ54AS646JT
5962-8995601LA	Active	Production	CDIP (JT) 24	15 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8995601LA SNJ54ALS646JT
5962-9052301LA	Active	Production	CDIP (JT) 24	15 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9052301LA SNJ54ALS648JT
SN74ALS646ADW	Active	Production	SOIC (DW) 24	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS646A
SN74ALS646ADWR	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS646A
SN74ALS648ADW	Active	Production	SOIC (DW) 24	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ALS648A
SN74AS646DW	Active	Production	SOIC (DW) 24	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	AS646
SNJ54ALS646JT	Active	Production	CDIP (JT) 24	15 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8995601LA SNJ54ALS646JT
SNJ54ALS648JT	Active	Production	CDIP (JT) 24	15 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9052301LA SNJ54ALS648JT
SNJ54AS646JT	Active	Production	CDIP (JT) 24	15 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8759501LA SNJ54AS646JT

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN54AS646, SN74AS646 :

- Catalog : [SN74AS646](#)
- Military : [SN54AS646](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALS646ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALS646ADWR	SOIC	DW	24	2000	350.0	350.0	43.0

TUBE



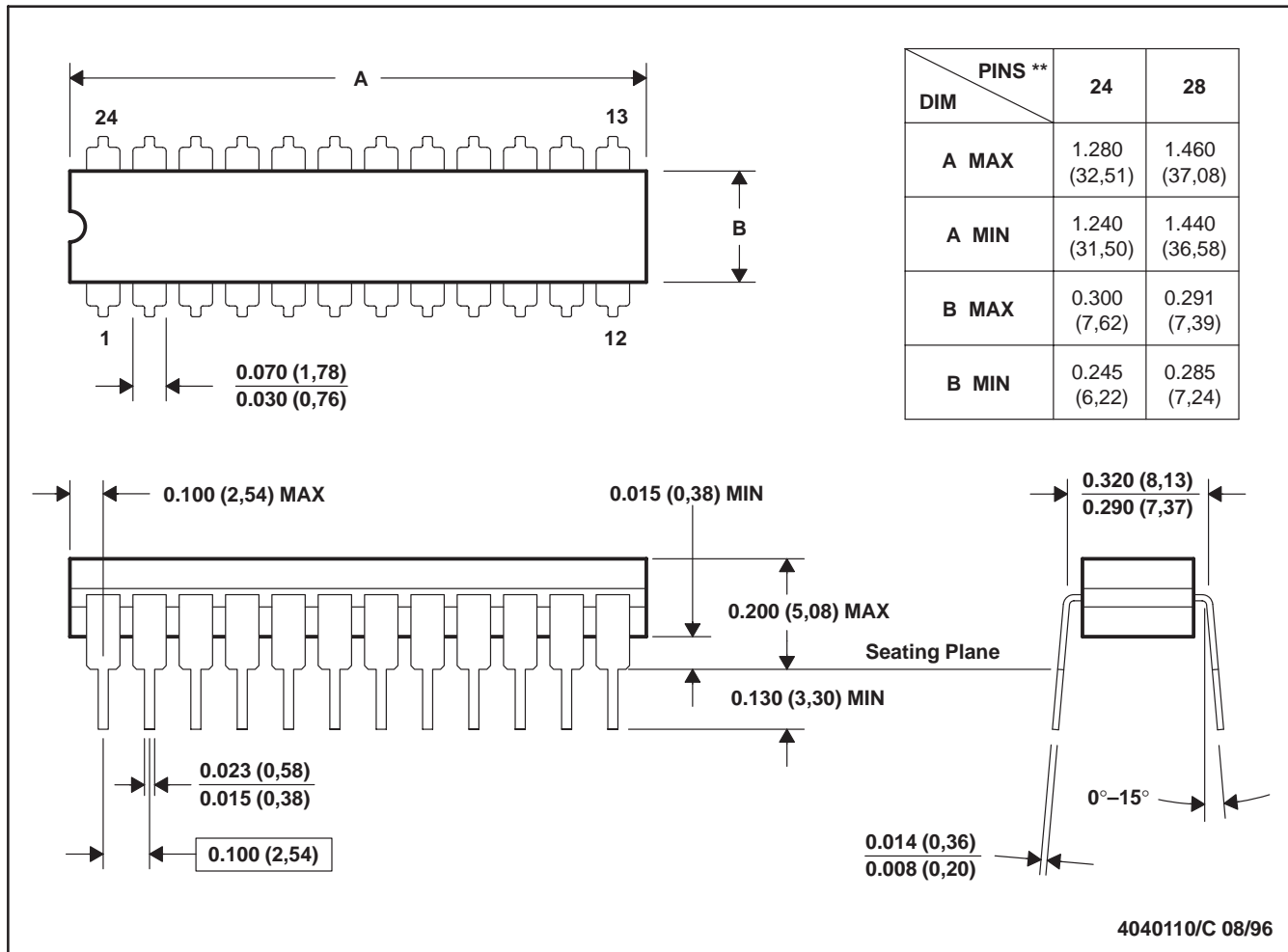
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN74ALS646ADW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74ALS648ADW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74AS646DW	DW	SOIC	24	25	506.98	12.7	4826	6.6

JT (R-GDIP-T**)

24 LEADS SHOWN

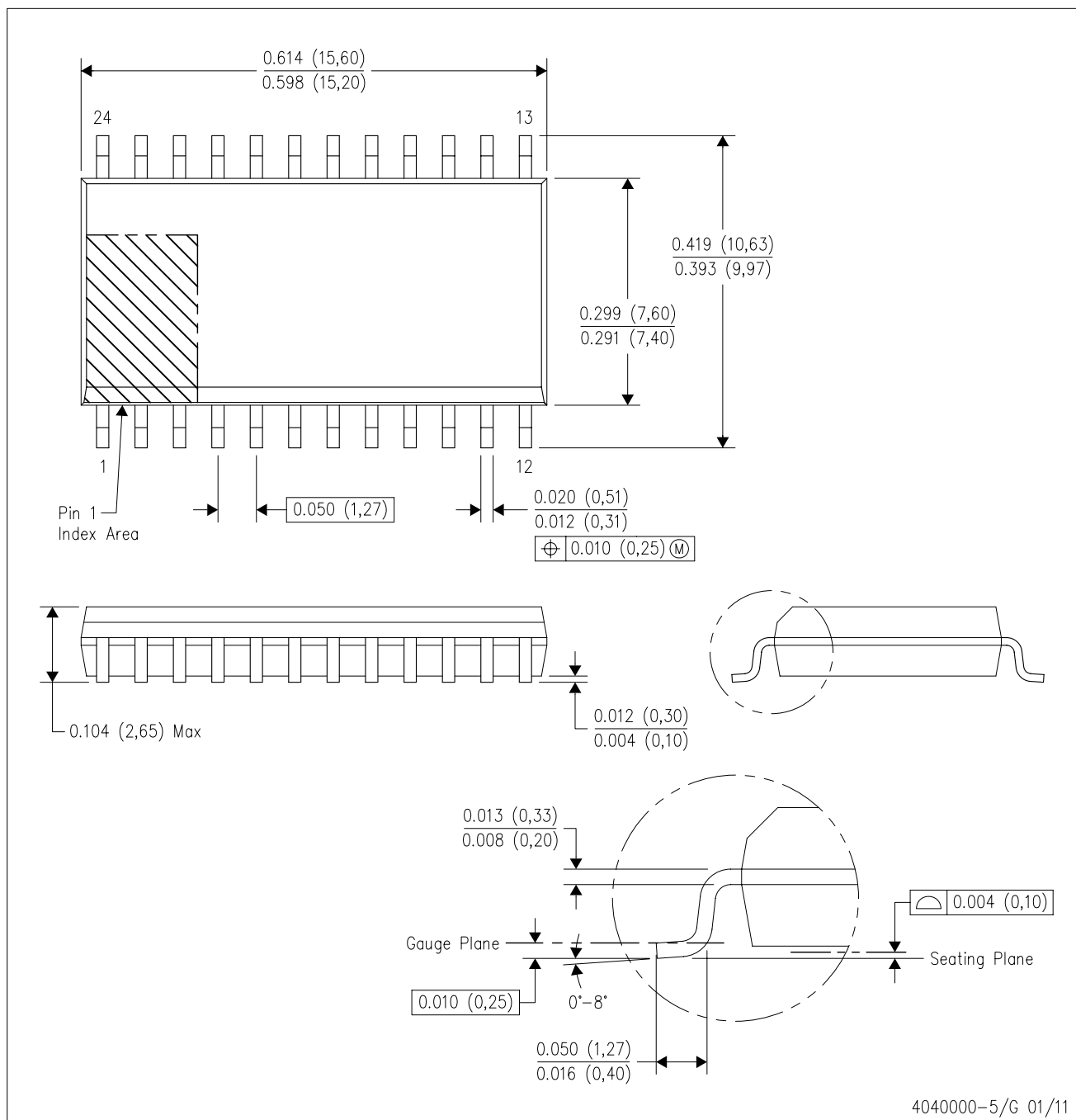
CERAMIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification.
 E. Falls within MIL STD 1835 GDIP3-T24, GDIP4-T28, and JEDEC MO-058 AA, MO-058 AB

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AD.

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